



SMT PHEMT LOW NOISE AMPLIFIER, 17 - 27 GHz

Typical Applications

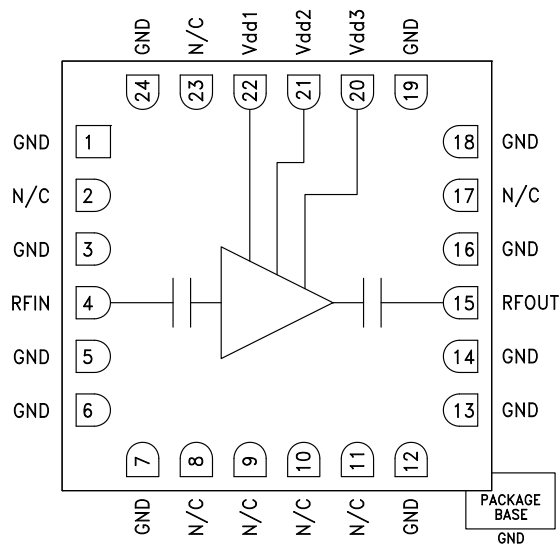
The HMC751LC4 is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios & VSAT
- Test Equipment and Sensors
- Military

Features

- Noise Figure: 2.2 dB
- Gain: 25 dB
- OIP3: +25 dBm
- Single Supply: +4V @ 73 mA
- 50 Ohm Matched Input/Output
- RoHS Compliant 4 x 4 mm Package

Functional Diagram



General Description

The HMC751LC4 is a high dynamic range GaAs pHEMT MMIC Low Noise Amplifier (LNA) housed in a leadless “Pb free” RoHS compliant SMT package. The HMC751LC4 provides 25 dB of small signal gain, 2.2 dB of noise figure and output IP3 of +25 dBm. The P1dB output power of +13 dBm also enables the LNA to function as a LO driver for balanced, I/Q or image reject mixers. The HMC751LC4 allows the use of surface mount manufacturing techniques.

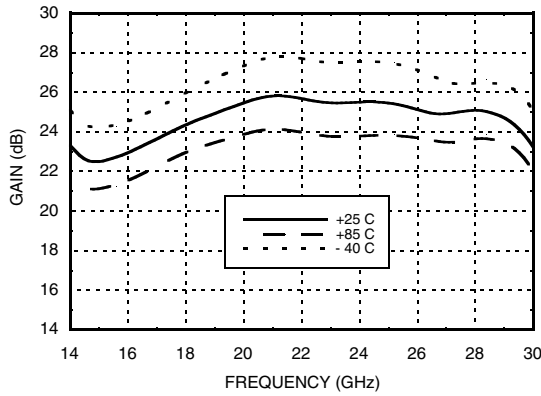
Electrical Specifications, $T_A = +25^\circ\text{C}$, Vdd 1, 2, 3 = +4V

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range	17 - 20			20 - 27			GHz
Gain	22	24		23	25		dB
Gain Variation Over Temperature		0.025			0.028		dB/ °C
Noise Figure		2.2	2.8		2.0	2.6	dB
Input Return Loss		17			15		dB
Output Return Loss		16			15		dB
Output Power for 1 dB Compression (P1dB)		13			13		dBm
Saturated Output Power (P _{sat})		15			15		dBm
Output Third Order Intercept (IP3)		25			25		dBm
Supply Current (I _{dd})(V _{dd} = +4V)	50	73	90	50	73	90	mA

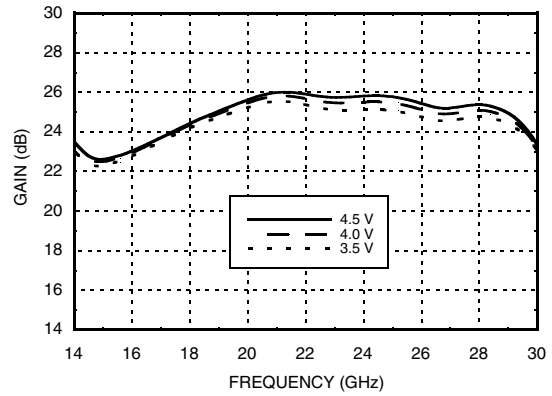


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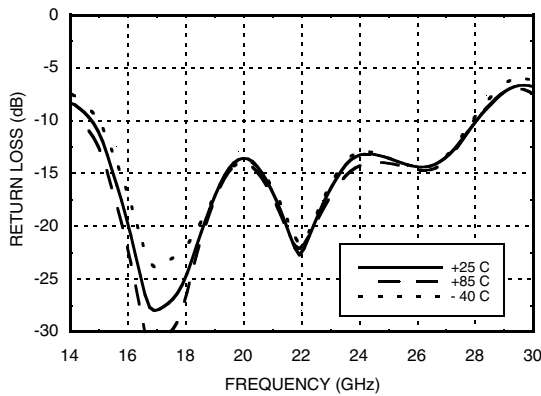
Gain vs. Temperature



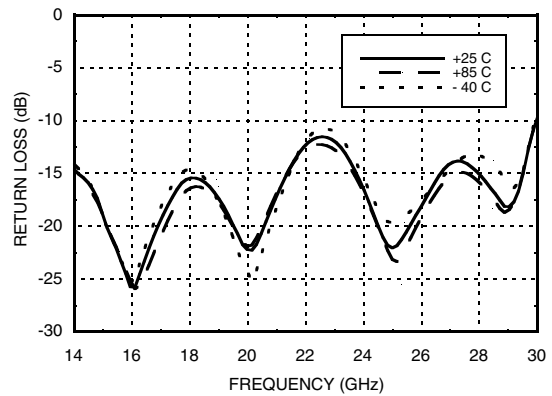
Gain vs. Supply Voltage



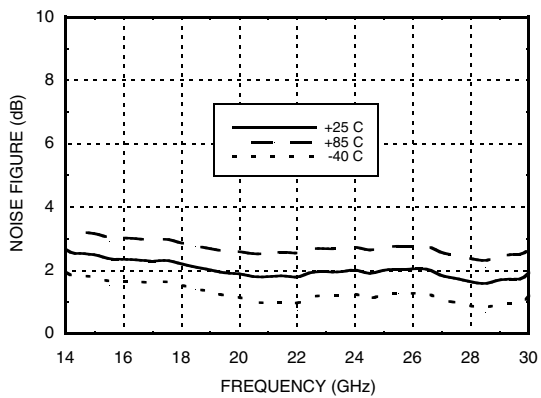
Input Return Loss vs. Temperature



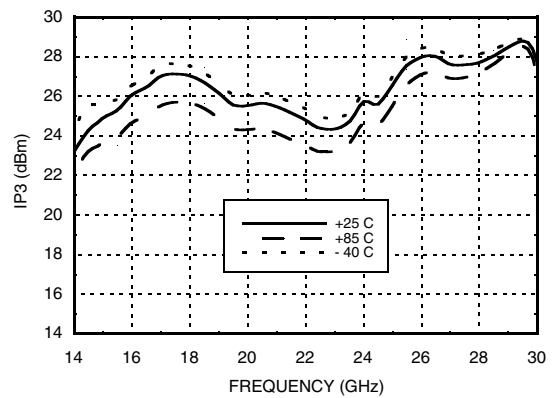
Output Return Loss vs. Temperature



Noise Figure vs. Temperature



Output IP3 vs. Temperature



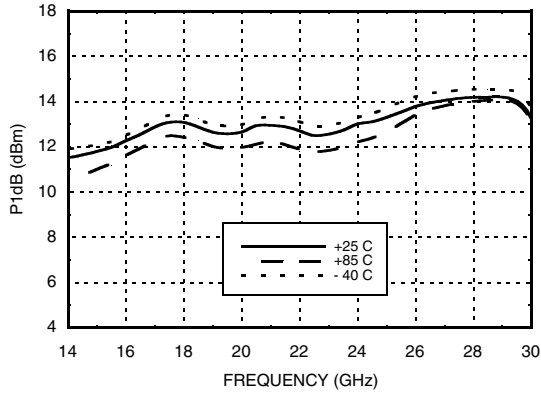
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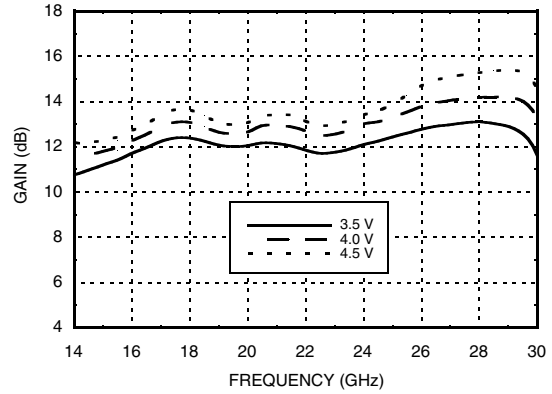


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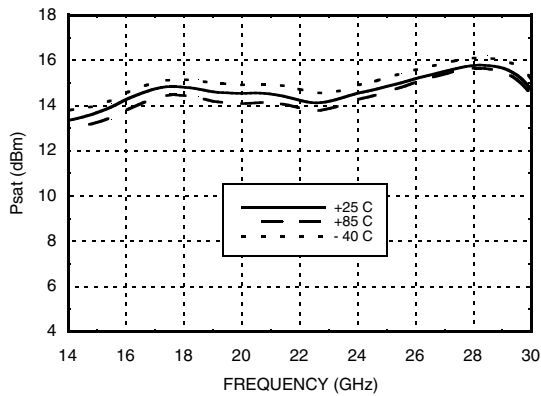
P1dB vs. Temperature



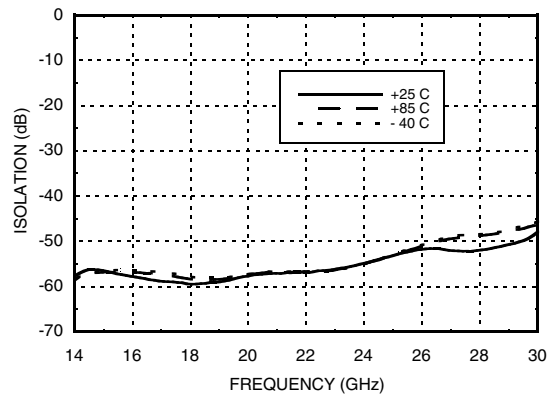
P1dB vs. Supply Voltage



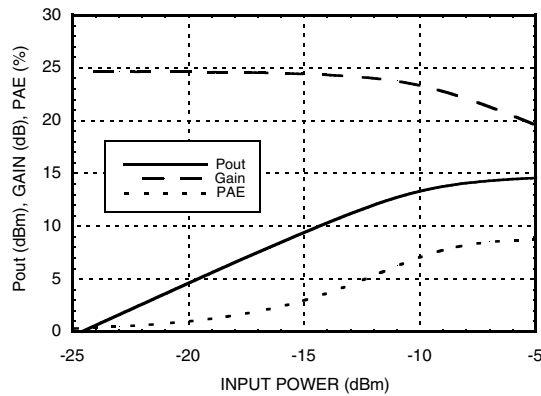
Psat vs. Temperature



Reverse Isolation vs. Temperature



Power Compression @ 21 GHz



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Absolute Maximum Ratings

Drain Bias Voltage (Vdd1, Vdd2, Vdd3)	+5.5 Vdc
RF Input Power (RFIN)(Vdd = +4 Vdc)	-5 dBm
Channel Temperature	175 °C
Continuous Pdiss (T= 85 °C) (derate 11.2 mW/°C above 85 °C)	1 W
Thermal Resistance (channel to ground paddle)	89 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

Typical Supply Current vs. Vdd

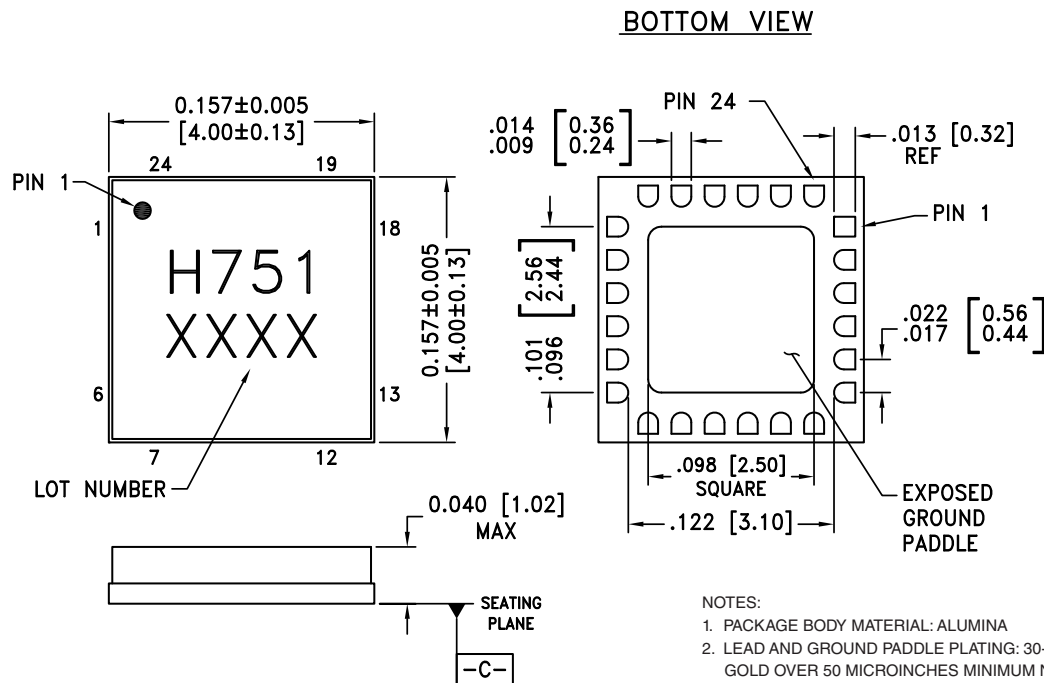
Vdd (Vdc)	Idd (mA)
+3.5	69
+4.0	73
+4.5	77

Note: Amplifier will operate over full voltage range shown above.



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[2]
HMC751LC4	Alumina, White	Gold over Nickel	MSL3 ^[1]	H751 XXXX

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX



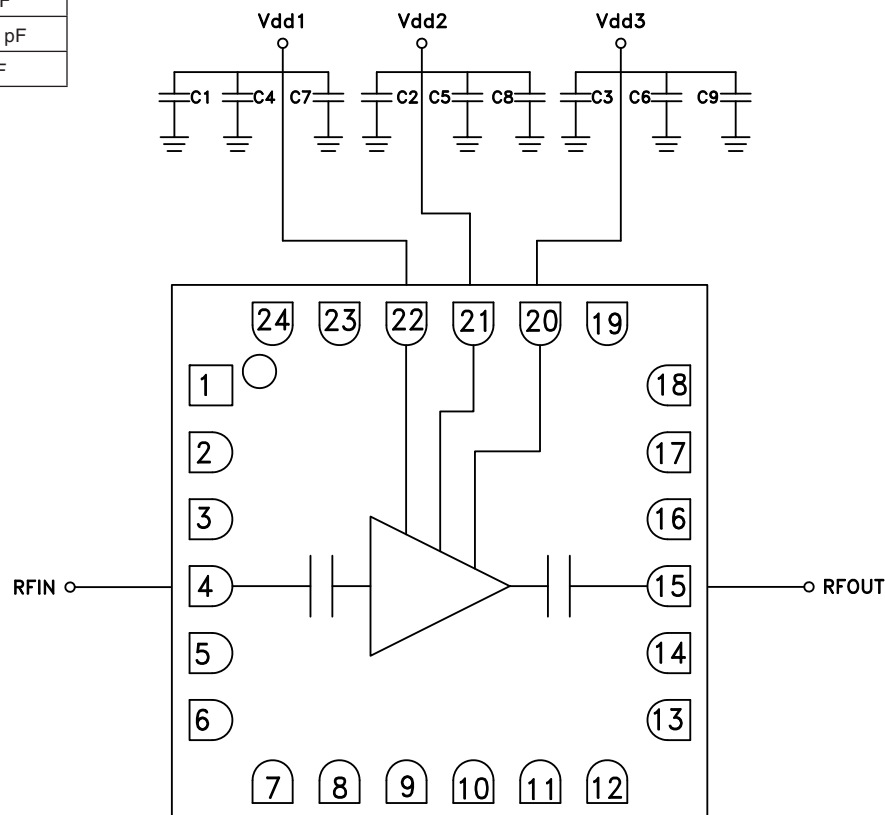
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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 3, 5 - 7, 12 - 14, 16, 18, 19, 24	GND	These pins and package bottom must be connected to RF/DC ground.	
2, 8 - 11, 17, 23	N/C	This pin may be connected to RF/DC ground. Performance will not be affected.	
4	RFIN	This pin is AC coupled and matched to 50 Ohms.	
15	RFOUT	This pin is AC coupled and matched to 50 Ohms.	
22, 21, 20	Vdd1, 2, 3	Power Supply Voltage for the amplifier. External bypass capacitors of 100 pF, 1,000 pF and 2.2 μF are required.	

Application Circuit

Component	Value
C1, C2, C3	100 pF
C4, C5, C6	1,000 pF
C7, C8, C9	2.2 μF



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